Bandpass photon detector with high efficiency for inver-

Review of Scientific Instruments 58, 710-711

DOI: 10.1063/1.1139244

Citation Report

#	Article	IF	CITATIONS
1	The experimental band structure of occupied and unoccupied states of titanium dichalcogenides. Journal of Physics C: Solid State Physics, 1987, 20, 4201-4212.	1.5	24
2	Inverse photoemission. Reports on Progress in Physics, 1988, 51, 1227-1294.	20.1	309
3	Conduction-band structure of graphite single crystals studied by angle-resolved inverse photoemission and target-current spectroscopy. Physical Review B, 1988, 38, 12582-12588.	3.2	49
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6	Surface study of the 83-K superconductorBi2Sr2CaCu2O8by low-energy electron diffraction and angle-resolved inverse photoemission spectroscopy. Physical Review B, 1989, 39, 7316-7319.	3.2	80
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19	The surface band gaps of Ge(001)2×1. Surface Science, 1992, 269-270, 854-859.	1.9	19
20	Performance of the inverse photoemission spectrometer with a new bandpass photon detector of narrow bandwidth and high sensitivity. Nuclear Instruments and Methods in Physics Research, Section A: Accelerators, Spectrometers, Detectors and Associated Equipment, 1993, 330, 140-143.	1.6	46
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